

PCA2003

32 kHz watch circuit with programmable adaptive motor pulse and pulse period

Rev. 5 — 1 May 2019

Product data sheet

1. General description

The PCA2003 is a CMOS integrated circuit for battery operated wrist watches with a 32 kHz quartz crystal as timing element and a bipolar 1 Hz stepping motor. The quartz crystal oscillator and the frequency divider are optimized for minimum power consumption. A timing accuracy of 1 ppm is achieved with a programmable, digital frequency adjustment.

To obtain the minimum overall power consumption for the watch, an automatic motor pulse adaptation function is provided. The circuit supplies only the minimum drive current, which is necessary to ensure a correct motor step. Changing the drive current of the motor is achieved by chopping the motor pulse with a variable duty cycle. The pulse period and the range of the variable duty cycle can be programmed to suit different types of motors. The automatic pulse adaptation scheme is based on a safe dynamic detection of successful motor steps.

A pad RESET is provided (used for stopping the motor) for accurate time setting and for accelerated testing of the watch.

2. Features and benefits

- Amplitude-regulated 32 kHz quartz crystal oscillator, with excellent frequency stability and high immunity to leakage currents
- Electrically programmable time calibration with 1 ppm resolution stored in One Time Programmable (OTP) memory
- The quartz crystal is the only external component connected
- Very low supply current, typical 90 nA
- One second output pulses for bipolar stepping motor
- Five different programmable output periods (1 s to 30 s)
- Minimum power consumption for the entire watch, due to self adaptation of the motor drive according to the required torque
- Reliable step detection circuit
- Motor pulse width, pulse modulation, and pulse adaptation range programmable in a wide range, stored in OTP memory
- Stop function for accurate time setting and power saving during shelf life
- Test mode for accelerated testing of the mechanical parts of the watch and the IC
- Test bits for type recognition



3. Applications

- Driver circuits for bipolar stepping motors
- High immunity motor drive circuits

4. Ordering information

Table 1. Ordering information

Type number	Topside marking	Package		
		Name	Description	Version
PCA2003U/10AC/1	PC 2003-1	wire bond die	8 bonding pads - 1.16 x 0.86 x 0.2 mm	PCA200xU

4.1 Ordering options

Table 2. Ordering options

Type number	Orderable part number	Package	Packing method	Minimum order quantity	Temperature
PCA2003U/10AC/1	PCA2003U/10AC/1,00	wire bond die	Sawn wafer on Film Frame Carrier (FFC)	15064	$T_{amb} = -10\text{ }^{\circ}\text{C}$ to $+60\text{ }^{\circ}\text{C}$
	PCA2003U/10AC/1Z	wire bond die	Reel 7" Q2 Die in tape reel DP	2000	$T_{amb} = -10\text{ }^{\circ}\text{C}$ to $+60\text{ }^{\circ}\text{C}$

5. Block diagram

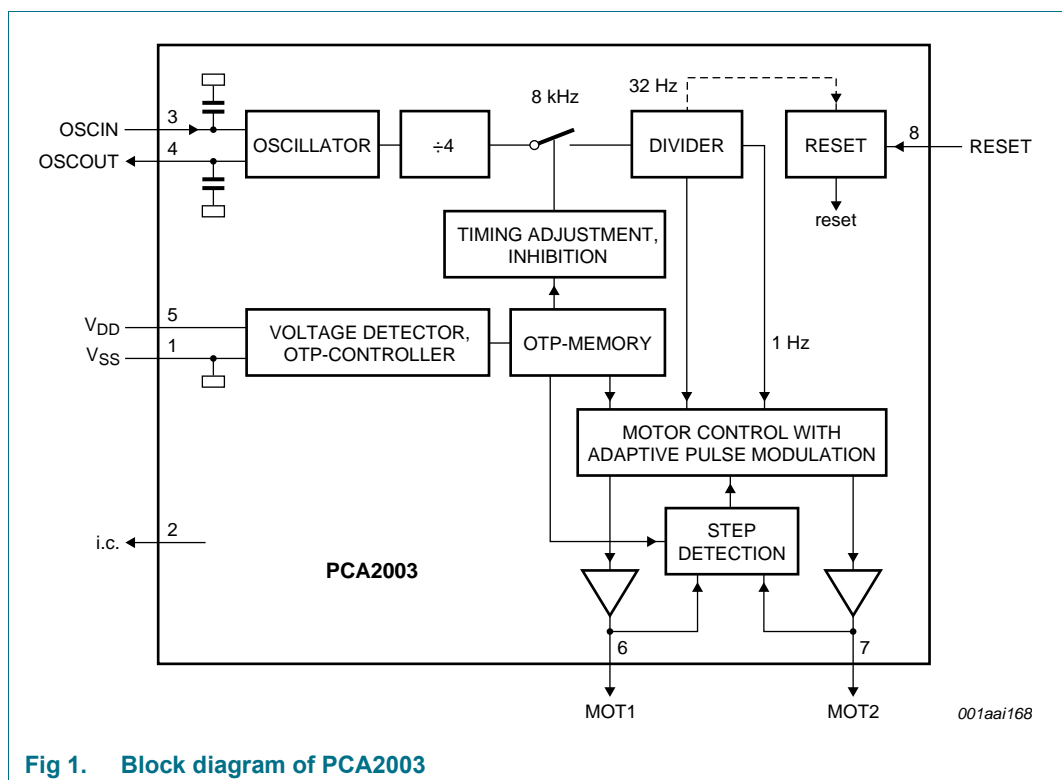
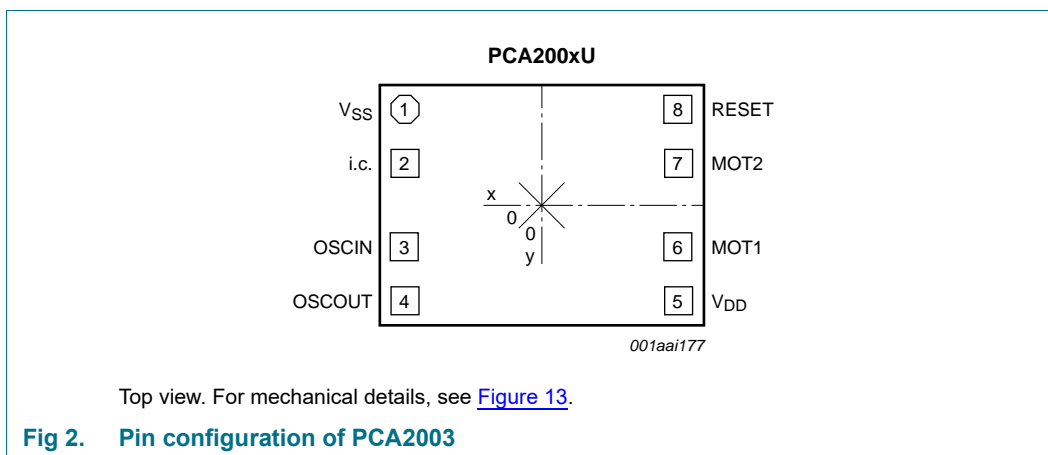


Fig 1. Block diagram of PCA2003

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
V _{SS}	1	ground
i.c.	2	internally connected
OSCIN	3	oscillator input
OSCOUT	4	oscillator output
V _{DD}	5	supply voltage
MOT1	6	motor 1 output
MOT2	7	motor 2 output
RESET	8	reset input

7. Functional description

7.1 Motor pulse

The motor output supplies pulses of different driving stages, depending on the torque required to turn on the motor. The number of different stages can be selected between three and six. With the exception of the highest driving stage, each motor pulse (t_p in [Figure 3](#) and [Figure 6](#)) is followed by a detection phase during which the motor movement is monitored, in order to check whether the motor has turned correctly or not.

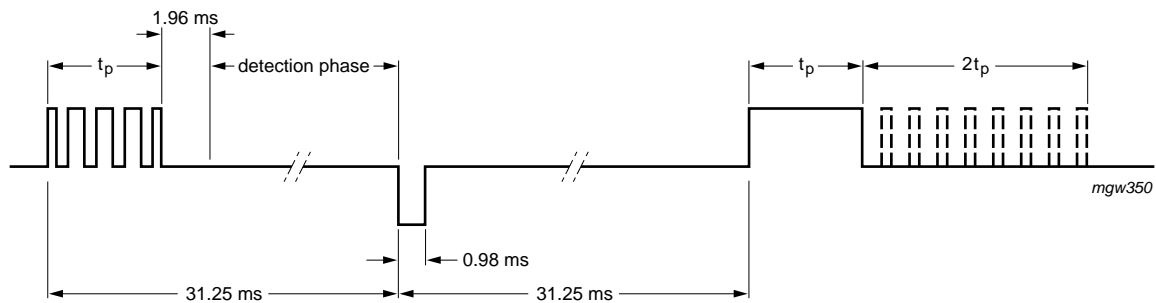


Fig 3. Correction sequence after failed motor step

If a missing step is detected, a correction sequence is generated (see [Figure 3](#)) and the driving stage is switched to the next level. The correction sequence consists of two pulses: first a short pulse in the opposite direction (0.98 ms, modulated with the maximum duty cycle) to give the motor a defined position, followed by a motor pulse of the strongest driving level. Every 4 minutes, the driving level is lowered again by one stage.

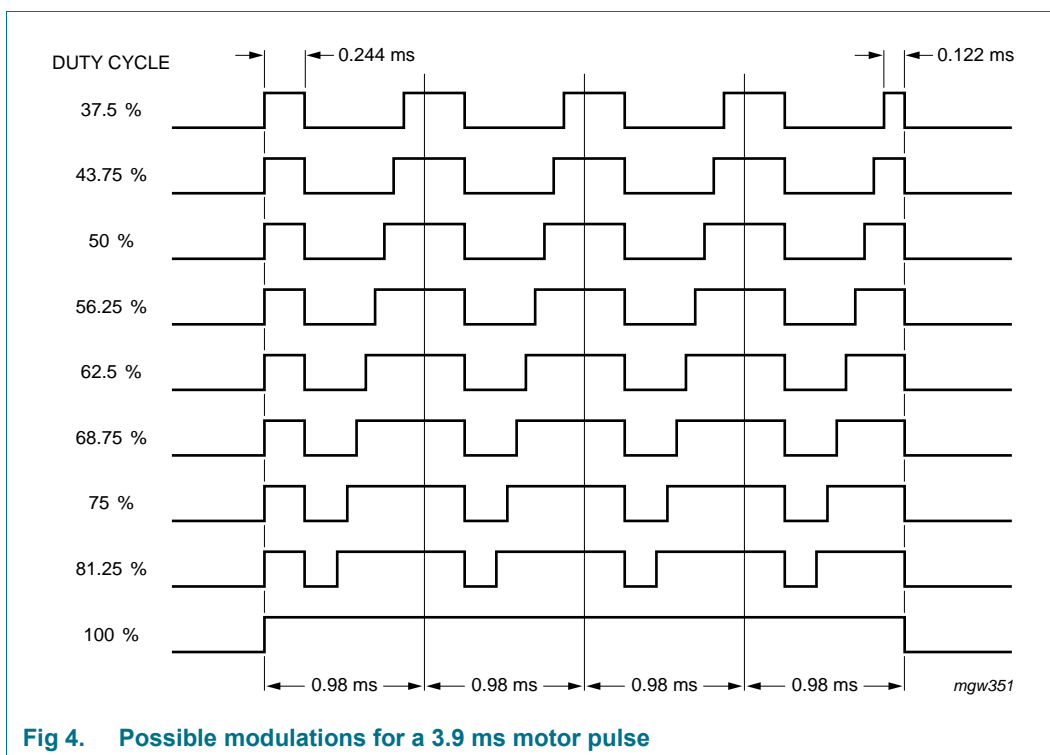
The motor pulse has a constant pulse width. The driving level is regulated by chopping the driving pulse with a variable duty cycle. The driving level starts from the programmed minimum value and increases by 6.25 % after each failed motor step. The strongest driving stage, which is not followed by a detection phase, is programmed separately.

Therefore, it is possible to program a larger energy gap between the pulses with step detection and the strongest, not monitored, pulse. This might be necessary to ensure a reliable and stable operation under adverse conditions (magnetic fields and vibrations). If the watch works in the highest driving stage, the driving level jumps after the 4-minute period directly to the lowest stage, and not just one stage lower.

To optimize the performance for different motors, the following parameters can be programmed:

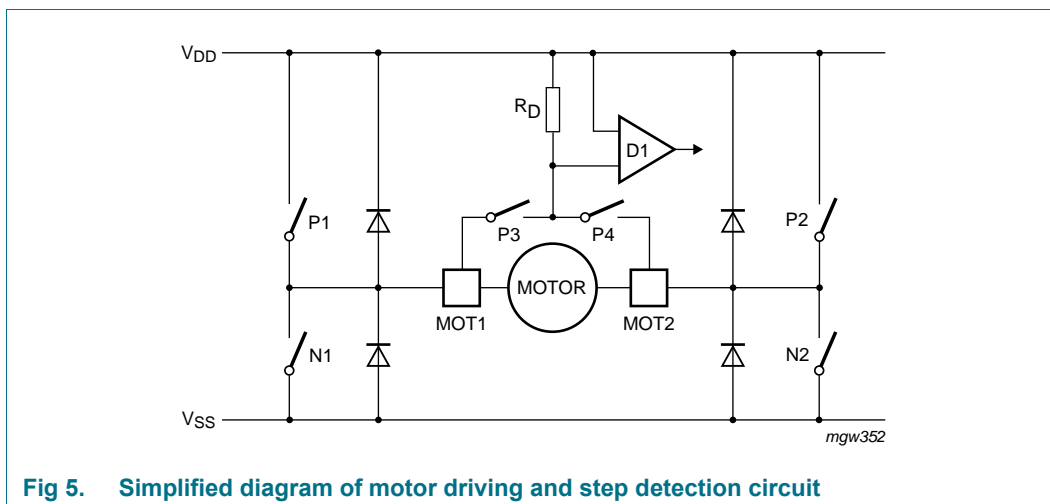
- Pulse width: 0.98 ms to 7.8 ms in steps of 0.98 ms
- Duty cycle of lowest driving level: 37.5 % to 56.25 % in steps of 6.25 %
- Number of driving levels (including the highest driving level): 3 to 6
- Duty cycle of the highest driving level: 75 % or 100 %
- Enlargement pulse for the highest driving level: on or off

The enlargement pulse has a duty cycle of 25 % and a pulse width which is twice the programmed motor pulse width. The repetition period for the chopping pattern is 0.98 ms. [Figure 4](#) shows an example of a 3.9 ms pulse.



7.2 Step detection

[Figure 5](#) shows a simplified diagram of the motor driving and step detection circuit, and [Figure 6](#) shows the step detection sequence and corresponding sampling current. Between the motor driving pulses, the switches P1 and P2 are closed, which means the motor is short-circuited. For a pulse in one direction, P1 and N2 are open, and P2 and N1 are closed with the appropriate duty cycle; for a pulse in the opposite direction, P2 and N1 are open, and P1 and N2 closed.



The step detection phase is initiated after the motor driving pulse. In phase 1 P1 and P2 are first closed for 0.98 ms and then in phase 2 all four drive switches (P1, N1, P2 and N2) are opened for 0.98 ms. As a result, the energy stored in the motor inductance is reduced as fast as possible.

The induced current caused by the residual motor movement is then sampled in phase 3 (closing P3 and P2) and in phase 4 (closing P1 and P4). For step detection in the opposite direction P1 and P4 are closed during phase 3 and P2 and P3 during phase 4 (see [Figure 6](#)).

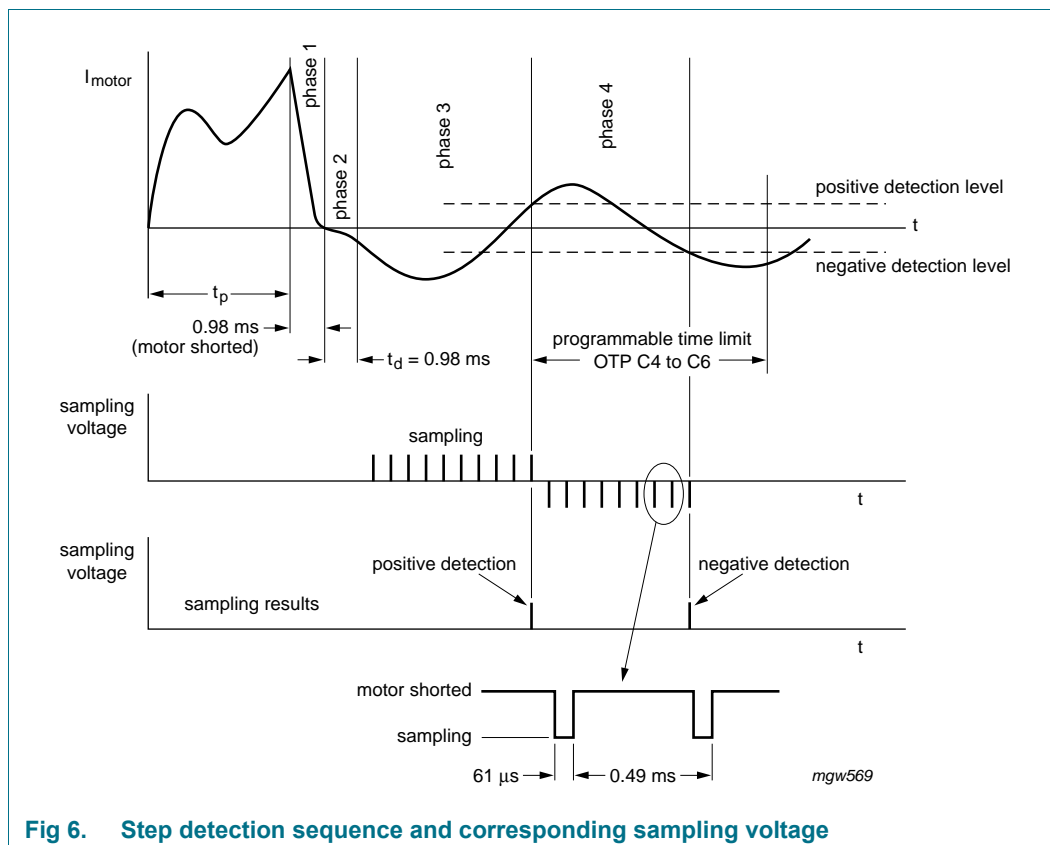


Fig 6. Step detection sequence and corresponding sampling voltage

The condition for a successful motor step is a positive step detection pulse (current in the same direction as in the driving phase) followed by a negative detection pulse within a given time limit. This time limit can be programmed between 3.9 ms and 10.7 ms (in steps of 0.98 ms) in order to ensure a safe and correct step detection under all conditions (for instance magnetic fields). The step detection phase stops after the last 31.25 ms, after the start of the motor driving pulse.

7.3 Time calibration

The quartz crystal oscillator has an integrated capacitance of 5.2 pF, which is lower than the specified capacitance (C_L) of 8.2 pF for the quartz crystal (see [Table 11](#)). Therefore, the oscillator frequency is typically 60 ppm higher than 32.768 kHz. This positive frequency offset is compensated by removing the appropriate number of 8192 Hz pulses in the divider chain (maximum 127 pulses), every 1 or 2 minutes. The time correction is given in [Table 4](#).

Table 4. Time calibration

Calibration period	Correction per step (n = 1)		Correction per step (n = 127)	
	ppm	Seconds per day	ppm	Seconds per day
1 minute	2.03	0.176	258	22.3
2 minutes	1.017	0.088	129	11.15

After measuring the effective oscillator frequency, the number of correction pulses must be calculated and stored together with the calibration period in the OTP memory (see [Section 7.7](#)).

The oscillator frequency can be measured at pad RESET, where a square wave signal with the frequency of $\frac{1}{1024} \times f_{osc}$ is provided. This frequency shows a jitter every minute or every two minutes, which originates from the time calibration, depending on the programmed calibration period.

Details on how to measure the oscillator frequency and the programmed inhibition time are given in [Section 7.10](#).

7.4 Reset

At pad RESET an output signal with a frequency of $\frac{1}{1024} \times f_{osc} = 32 \text{ Hz}$ is provided.

Connecting pad RESET to V_{DD} stops the motor drive and opens all four (P1, N1, P2 and N2) driver switches (see [Figure 5](#)). Connecting pad RESET to V_{SS} activates the test mode. In this mode the motor output frequency is 32 Hz, which can be used to test the mechanical function of the watch.

After releasing the pad RESET, the motor starts exactly one second later with the smallest duty cycle and with the opposite polarity to the last pulse before stopping. The debounce time for the RESET function is between 31 ms and 62 ms.

7.5 Programming possibilities

The programming data is stored in OTP cells (EPROM cells). At delivery, all memory cells are in state 0. The cells can be programmed to the state 1, but then there is no more set back to state 0. The programming data is organized in an array of four 8-bit words (see [Table 5](#)): word A contains the time calibration, words B and C contain the setting for the motor pulses and word D contains the type recognition.

Table 5. Words and bits

Word	Bit							
	1	2	3	4	5	6	7	8
A	number of 8192 Hz pulses to be removed							calibration period
B	lowest stage: duty cycle		number of driving stages		highest stage: duty cycle	pulse stretching	output period	
C	pulse width			maximum time delay between positive and negative detection pulses			output period	factory test bit
D	type				factory test bits			

Table 6. Description of word A bits

Bit	Value	Description
Inhibition time		
1 to 7	-	adjust the number of the 8 192 Hz pulses to be removed; bit 1 is the MSB and bit 7 is the LSB
Calibration period		
8	0	1 minute
	1	2 minutes

Table 7. Description of word B bits

Bit	Value	Description
Duty cycle lowest driving stage		
1 to 2	00	37.5 %
	01	43.75 %
	10	50 %
	11	56.25 %
Number of driving stages		
3 to 4	00	3
	01	4
	10	5
	11	6 ^[1]
Duty cycle highest driving stage		
5	0	75 % ^[2]
	1	100 %
Pulse stretching		
6	0	no pulse stretching
	1	pulse of $2 \times t_p$ and duty cycle of 25 % are added
Output period		
7 to 8	00	1 s
	01	5 s
	10	10 s
	11	20 s

[1] Including the highest driving stage, which one has no motor step detection.

[2] If the maximum duty cycle of 75 % is selected, not all programming combinations are possible since the second highest level must be smaller than the highest driving level.

Table 8. Description of word C bits

Bit	Value	Description
Pulse width t_p		
1 to 3	000	0.98 ms
	001	1.95 ms
	010	2.90 ms
	011	3.90 ms
	100	4.90 ms
	101	5.90 ms
	110	6.80 ms
	111	7.80 ms
Time delay $t_{d(max)}$ [1]		
4 to 6	000	3.91 ms
	001	4.88 ms
	010	5.86 ms
	011	6.84 ms
	100	7.81 ms
	101	8.79 ms
	110	9.77 ms
	111	10.74 ms
Output period		
7	0	bit 7 and 8 of word B active
	1	30 s, bit 7 and 8 of word B inactive
Factory test bit		
8	-	-

[1] Between positive and negative detection pulses.

Byte D is read to determine which type of the PCA200x family is used in a particular application.

Table 9. Description of word D bits

Bit	Value	Description
Type recognition		
1 to 4	0000	PCA2002
	1000	PCA2000
	0100	PCA2001
	1100	PCA2003
Factory test bits		
5 to 8	-	-

7.6 Programming procedure

For a watch it is essential that the timing calibration can be made after the watch is fully assembled. In this situation, the supply pads are often the only terminals which are still accessible.

Writing to the OTP cells and performing the related functional checks is achieved in the PCA2003 by modulating the supply voltage. The necessary control circuit consists basically of a voltage level detector, an instruction counter which determines the function to be performed, and an 8-bit shift register which allows writing to the OTP cells of an 8-bit word in one step and acts as a data pointer for checking the OTP content.

There are six different instruction states (state 3 and state 5 are handled as state 4):

- State 1: measurement of the quartz crystal oscillator frequency (divided by 1024)
- State 2: measurement of the inhibition time
- State 3: write/check word A
- State 4: write/check word B
- State 5: write/check word C
- State 6: check word D (type recognition)

Each instruction state is switched on with a pulse to $V_{P(prog)(start)}$. After this large pulse, an initial waiting time of t_0 is required. The programming instructions are then entered by modulating the supply voltage with small pulses (amplitude $V_{P(mod)}$ and pulse width t_{mod}). The first small pulse defines the start time, the following pulses perform three different functions, depending on the time delay (t_d) from the preceding pulse (see [Figure 7](#), [Figure 8](#), [Figure 11](#) and [Figure 12](#)):

- $t_d = t_1$ (0.7 ms); increments the instruction counter
- $t_d = t_2$ (1.7 ms); clocks the shift register with data = logic 0
- $t_d = t_3$ (2.7 ms); clocks the shift register with data = logic 1

The programming procedure requires a stable oscillator. This means that a waiting time, determined by the start-up time of the oscillator is necessary after power-on of the circuit.

After the $V_{P(prog)(start)}$ pulse, the instruction counter is in state 1 and the data shift register is cleared.

The instruction state ends with a second pulse to $V_{P(prog)(stop)}$ or with a pulse to V_{store} .

In any case, the instruction states are terminated automatically 2 seconds after the last supply modulation pulse.

7.7 Programming the memory cells

Applying the two-stage programming pulse (see [Figure 7](#)) transfers the stored data in the shift register to the OTP cells.

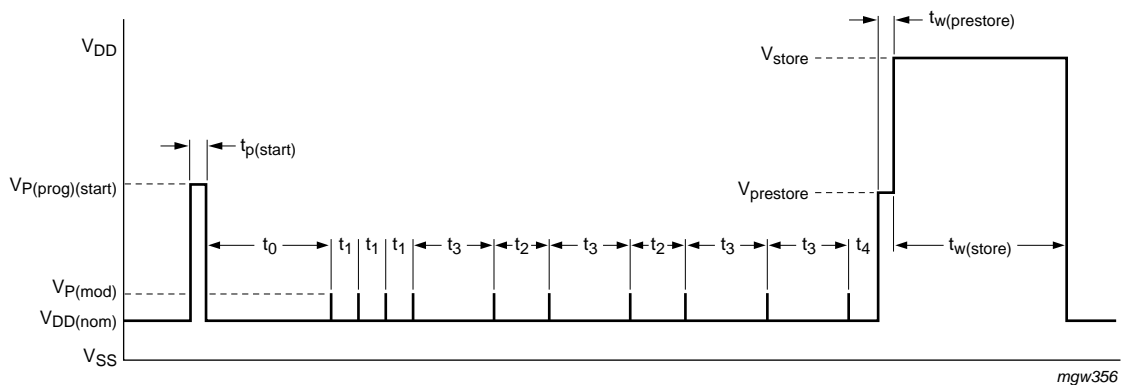
Perform the following to program a memory word:

1. Starting with a $V_{P(prog)(start)}$ pulse wait for the time period t_0 then set the instruction counter to the word to be written ($t_d = t_1$).

2. Enter the data to be stored in the shift register ($t_d = t_2$ or t_3). LSB first (bit 8) and the MSB last (bit 1).
3. Applying the two-stage programming pulse V_{prestore} followed by V_{store} stores the word. The delay between the last data bit and the prestore pulse V_{prestore} is $t_d = t_4$. Store the word by raising the supply voltage to V_{store} ; the delay between the last data bit and the store pulse is t_d .

The example shown in [Figure 7](#) performs the following functions:

- Start
- Setting instruction counter to state 4 (word B)
- Entering data word 110101 into the shift register (sequence: LSB first and MSB last)
- Writing to the OTP cells for word B



$V_{\text{DD(nom)}}$: nominal supply voltage.

The example shows the programming of B = 110101 (the sequence is MSB first and LSB last).

Fig 7. Supply voltage modulation for programming

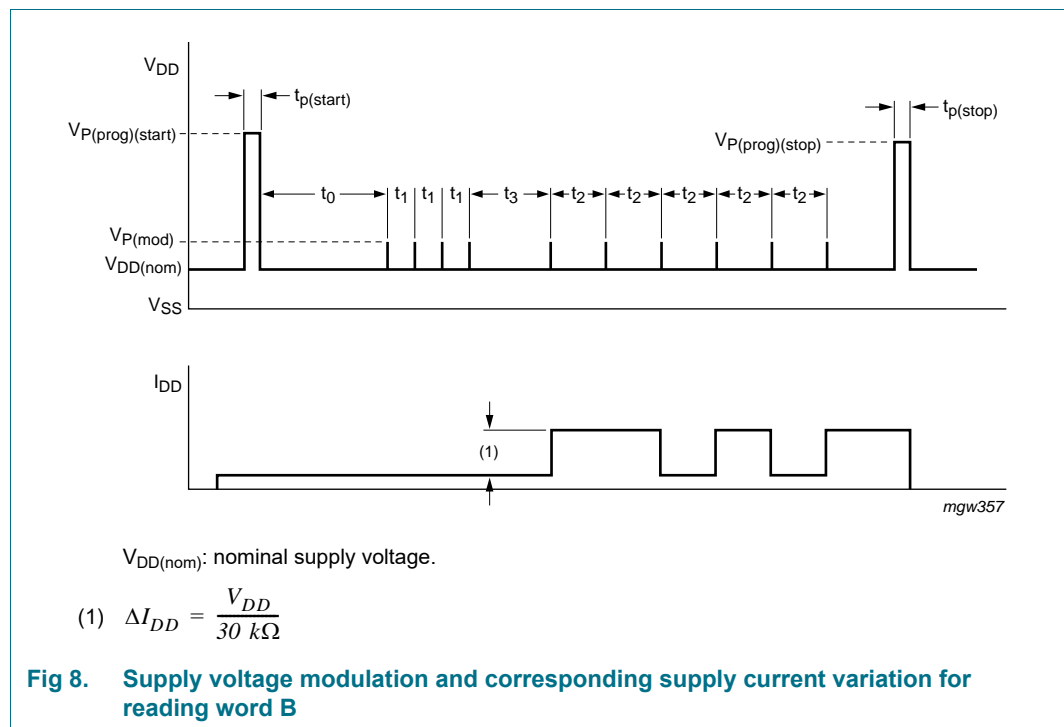
7.8 Checking memory content

The stored data of the OTP array can be checked bit wise by measuring the supply current. The array word is selected by the instruction state and the bit is addressed by the shift register.

To read a word, the word is first selected ($t_d = t_1$), and a logic 1 is written into the first cell of the shift register ($t_d = t_3$). This logic 1 is then shifted through the entire shift register ($t_d = t_2$), so that it points with each clock pulse to the next bit.

If the addressed OTP cell contains a logic 1, a 30 kΩ resistor is connected between V_{DD} and V_{SS} , which increases the supply current accordingly.

[Figure 8](#) shows the supply voltage modulation for reading word B, with the corresponding supply current variation for word B = 110101 (sequence: first MSB and last LSB).



7.9 Frequency tuning of assembled watch

Figure 9 shows the test set-up for frequency tuning the assembled watch.

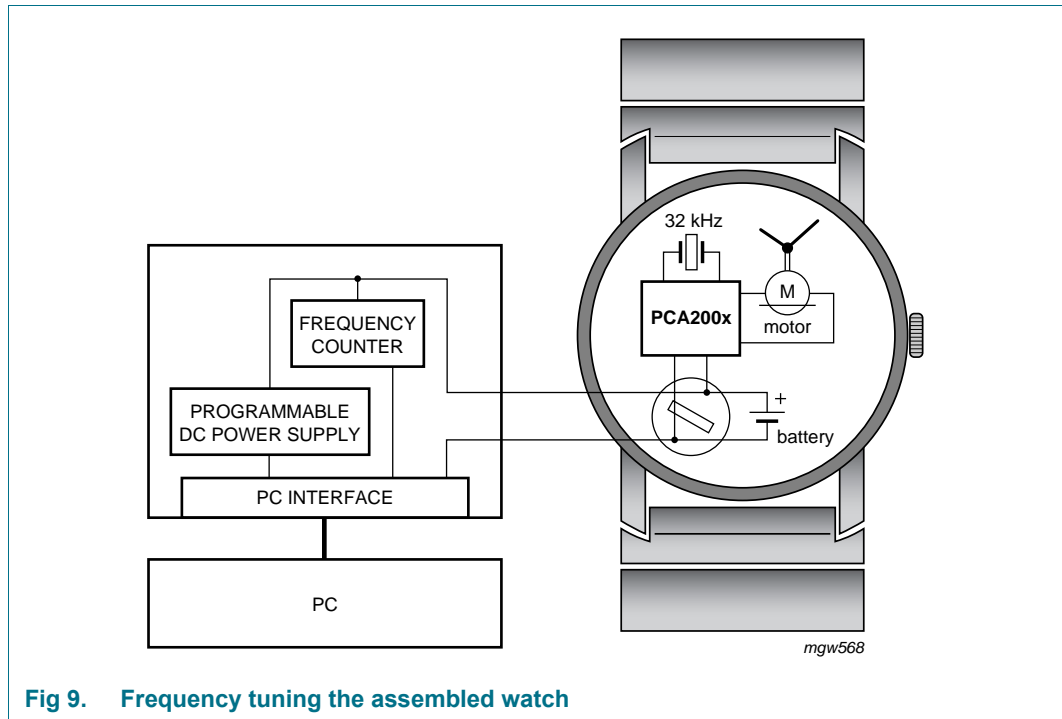


Fig 9. Frequency tuning the assembled watch

7.10 Measurement of oscillator frequency and inhibition time

The output of the two measuring states can either be monitored directly at pad RESET or as a modulation of the supply voltage (a modulating resistor of 30 k Ω is connected between V_{DD} and V_{SS} when the signal at pad RESET is at HIGH-level).

The supply voltage modulation must be followed as shown in Figure 10 in order to guarantee the correct start-up of the circuit during production and testing.

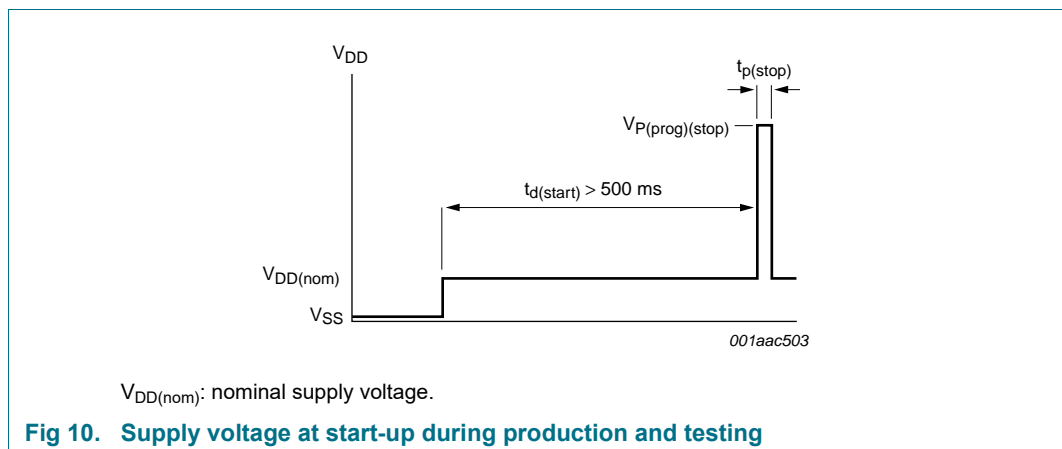


Fig 10. Supply voltage at start-up during production and testing

Measuring states:

- State 1: quartz crystal oscillator frequency divided by 1024; state 1 starts with a pulse to V_P and ends with a second pulse to V_P
- State 2: inhibition time has a value of $n \times 0.122$ ms. A signal with periodicity of 31.25 ms + $n \times 0.122$ ms appears at pad RESET and as current modulation at pad V_{DD} (see [Figure 11](#) and [Figure 12](#))

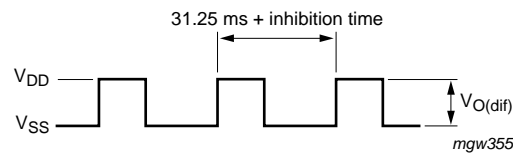
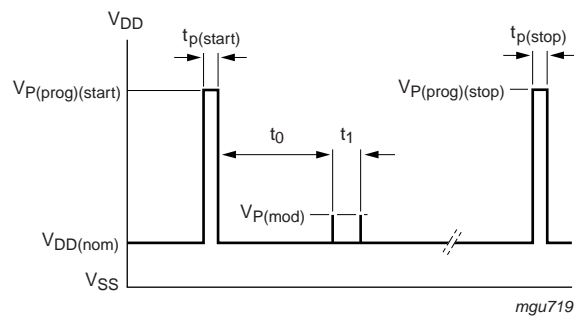


Fig 11. Output waveform at pad RESET for instruction state 2



$V_{DD(nom)}$: nominal supply voltage.

Fig 12. Supply voltage modulation for starting and stopping of instruction state 2

7.11 Customer testing

Connecting pad RESET to V_{SS} activates the test mode. In this test mode, the motor output frequency is 8 Hz; the duty cycle reduction and battery check occurs every second, instead of every 4 minutes.

8. Limiting values

Table 10. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage	$V_{SS} = 0\text{ V}$	[1][2] -1.8	+7.0	V
V_I	input voltage	on all supply pins	-0.5	+7.5	V
t_{sc}	short circuit duration time	output	-	indefinite	s
T_{amb}	ambient temperature		-10	+60	°C
V_{ESD}	electrostatic discharge voltage	HBM	[3] -	±2000	V
		MM	[4] -	±200	V
I_{lu}	latch-up current		[5] -	100	mA
T_{stg}	storage temperature		[6] -30	+100	°C

- [1] When writing to the OTP cells, the supply voltage (V_{DD}) can be raised to a maximum of 12 V for a time period of 1 s.
- [2] Connecting the battery with reversed polarity does not destroy the circuit, but in this condition a large current flows, which rapidly discharges the battery.
- [3] Pass level; Human Body Model (HBM), according to [Ref. 4 "JESD22-A114"](#).
- [4] Pass level; Machine Model (MM), according to [Ref. 5 "JESD22-A115"](#).
- [5] Pass level; latch-up testing according to [Ref. 6 "JESD78"](#) at maximum ambient temperature ($T_{amb(max)}$).
- [6] According to the NXP store and transport requirements (see [Ref. 8 "NX3-00092"](#)) the devices have to be stored at a temperature of +8 °C to +45 °C and a humidity of 25 % to 75 %. For long term storage products deviant conditions are described in that document.

9. Characteristics

Table 11. Characteristics

$V_{DD} = 1.55\text{ V}$; $V_{SS} = 0\text{ V}$; $f_{osc} = 32.768\text{ kHz}$; $T_{amb} = 25\text{ °C}$; quartz crystal: $R_S = 40\text{ k}\Omega$, $C_1 = 2\text{ fF}$ to 3 fF , $C_L = 8.2\text{ pF}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Supply							
V _{DD}	supply voltage	normal operating mode; T _{amb} = −10 °C to +60 °C	1.1	1.55	3.60	V	
ΔV _{DD}	supply voltage variation	ΔV/Δt = 1 V/μs	-	-	0.25	V	
I _{DD}	supply current	between motor pulses	-	90	120	nA	
		between motor pulses at V _{DD} = 3.5 V	-	120	180	nA	
		T _{amb} = −10 °C to +60 °C	-	-	200	nA	
		stop mode; pad RESET connected to V _{DD}	-	100	135	nA	
Motor output							
V _{sat}	saturation voltage	R _{motor} = 2 kΩ; T _{amb} = −10 °C to +60 °C	[1]	-	150	200	mV
Z _{o(sc)}	output impedance (short circuit)	between motor pulses; I _{motor} < 1 mA	-	200	300	Ω	
Oscillator							
V _{start}	start voltage		1.1	-	-	V	
g _m	transconductance	V _{i(osc)} ≤ 50 mV (p-p)	5	10	-	μS	
t _{startup}	start-up time		-	0.3	0.9	s	
Δf/f	frequency stability	ΔV _{DD} = 100 mV	-	0.05	0.20	ppm	
C _{L(itg)}	integrated load capacitance		4.3	5.2	6.3	pF	
R _{par}	parasitic resistance	allowed resistance between adjacent pads	20	-	-	MΩ	
Pad RESET							
f _o	output frequency		-	32	-	Hz	
V _{O(dif)}	differential output voltage	R _L = 1 MΩ; C _L = 10 pF	[2]	1.4	-	V	
t _r	rise time	R _L = 1 MΩ; C _L = 10 pF	[2]	-	1	-	μs
t _f	fall time	R _L = 1 MΩ; C _L = 10 pF	[2]	-	1	-	μs
I _{i(AV)}	average input current	pad RESET connected to V _{DD} or V _{SS}	-	10	20	nA	

[1] $P1 + \dots + P4 + N1 + N2$ (see [Section 7.2](#)).

[2] R_L and C_L are a load resistor and load capacitor, externally connected to pad RESET.

10. OTP programming characteristics

Table 12. Specifications for OTP programming

See [Figure 7](#), [Figure 8](#) and [Figure 12](#).

Symbol	Parameter ^[1]	Conditions	Min	Typ	Max	Unit
V _{DD}	supply voltage	during programming procedure	1.5	-	3.0	V
V _{P(prog)(start)}	programming supply voltage (start)		6.6	-	6.8	V
V _{P(prog)(stop)}	programming supply voltage (stop)		6.2	-	6.4	V
V _{P(mod)}	supply voltage modulation	for entering instructions, referred to V _{DD}	320	350	380	mV
V _{prestore}	prestore voltage	for prestore pulse	6.2	-	6.4	V
V _{store}	store voltage	for writing to the OTP cells	9.9	10.0	10.1	V
I _{store}	store current	for writing to the OTP cells	-	-	10	mA
t _{p(start)}	start pulse width		8	10	12	ms
t _{p(stop)}	pulse width of stop pulse		0.05	-	0.5	ms
t _{mod}	modulation pulse width		25	30	40	μs
t _{w(prestore)}	prestore pulse width		0.05	-	0.5	ms
t _{w(store)}	store pulse width	for writing to the OTP cells	95	100	110	ms
t ₀	time 0	waiting time after start pulse	20	-	30	ms
t ₁	time 1	pulse distance for incrementing the state counter	0.6	0.7	0.8	ms
t ₂	time 2	pulse distance for clocking the data register with data = logic 0	1.6	1.7	1.8	ms
t ₃	time 3	pulse distance for clocking the data register with data = logic 1	2.6	2.7	2.8	ms
t ₄	time 4	waiting time for writing to OTP cells	0.1	0.2	0.3	ms
SR	slew rate	for modulation of the supply voltage	0.5	-	5.0	V/μs
R _{mod}	modulation resistance	supply current modulation read-out resistor	18	30	45	kΩ

[1] Program each word once only.

11. Bare die outline

Wire bond die; 8 bonding pads

PCA200xU

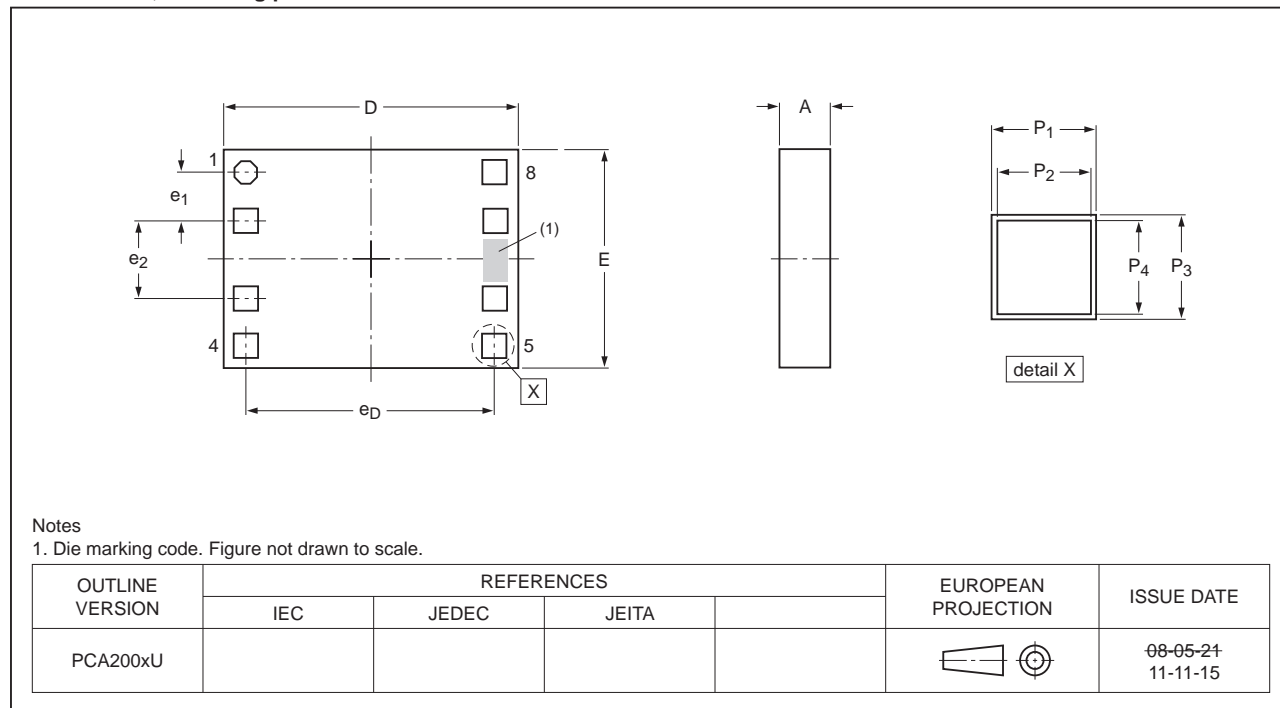


Fig 13. Bare die outline of PCA2003U (for dimensions see [Table 13](#), for pin location see [Table 14](#))

Table 13. Dimensions of PCA2003U

Original dimensions are in mm.

Unit (mm)	A	D	E	e ₁	e ₂	e _D	P ₁	P ₂	P ₃	P ₄
max	0.22	-	-	-	-	-	0.099	0.089	0.099	0.089
nom	0.20	1.16	0.86	0.17	0.32	0.96	0.096	0.086	0.096	0.086
min	0.18	-	-	-	-	-	0.093	0.083	0.093	0.083

Table 14. Bonding pad description

Symbol	Pin	X ^[1]	Y ^[1]	Type	Description
V _{SS} ^[2]	1	−480	+330	supply	ground
i.c. ^[3]	2	−480	+160	-	internally connected
OSCIN	3	−480	−160	input	oscillator input
OSCOUT	4	−480	−330	output	oscillator output
V _{DD}	5	+480	−330	supply	supply voltage
MOT1	6	+480	−160	output	motor 1 output
MOT2	7	+480	+160	output	motor 2 output
RESET	8	+480	+330	input	reset input

[1] All coordinates are referenced, in μm , to the center of the die (see [Figure 13](#)).

[2] The substrate (rear side of the chip) is connected to V_{SS}. Therefore the die pad must be either floating or connected to V_{SS}.

[3] Pad i.c. is used for factory tests; in normal operation it should be left open-circuit, and it has an internal pull-down resistance to V_{SS}.

12. Abbreviations

Table 15. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
HBM	Human Body Model
LSB	Least Significant Bit
MM	Machine Model
MSB	Most Significant Bit
OTP	One Time Programmable

13. References

- [1] **AN10706** — Handling bare die
- [2] **IEC 60134** — Rating systems for electronic tubes and valves and analogous semiconductor devices
- [3] **IEC 61340-5** — Protection of electronic devices from electrostatic phenomena
- [4] **JESD22-A114** — Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)
- [5] **JESD22-A115** — Electrostatic Discharge (ESD) Sensitivity Testing Machine Model (MM)
- [6] **JESD78** — IC Latch-Up Test
- [7] **JESD625-A** — Requirements for Handling Electrostatic-Discharge-Sensitive (ESDS) Devices
- [8] **NX3-00092** — NXP store and transport requirements

14. Revision history

Table 16. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PCA2003 v.5	20190501	Product data sheet	-	PCA2003 v.4
Modifications:	• Added PCA2003U/10AC/1Z			
PCA2003 v.4	20111125	Product data sheet	-	PCA2003_3
Modifications:	• Added die marking information			
PCA2003_3	20100507	Product data sheet	-	PCA2003_2
PCA2003_2	20090721	Product data sheet	-	PCA2003_1
PCA2003_1	20081215	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 1 May 2019

Document identifier: PCA2003

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